

# HiPerFRED

$$V_{RRM} = 200 \text{ V}$$

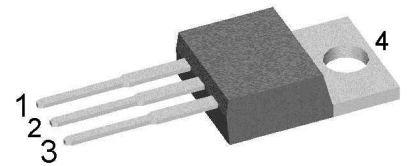
$$I_{FAV} = 2 \times 15 \text{ A}$$

$$t_{rr} = 35 \text{ ns}$$

High Performance Fast Recovery Diode  
 Low Loss and Soft Recovery  
 Common Cathode

Part number

**DPG30C200PB**



Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low  $I_{rm}$ -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{rm}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

### Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Disclaimer Notice

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| Fast Diode |  |  |           | Ratings                      |      |      |               |
|------------|--|--|-----------|------------------------------|------|------|---------------|
| Symbol     | Definition                                   | Conditions   |           | min.                         | typ. | max. | Unit          |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage |  |           |                              |      | 200  | V             |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     |  |           |                              |      | 200  | V             |
| $I_R$      | reverse current, drain current               | $V_R = 200\text{ V}$   |           | $T_{VJ} = 25^\circ\text{C}$  |      | 1    | $\mu\text{A}$ |
|            |  | $V_R = 200\text{ V}$   |           | $T_{VJ} = 150^\circ\text{C}$ |      | 0.08 | mA            |
| $V_F$      | forward voltage drop                         | $I_F = 15\text{ A}$  |           | $T_{VJ} = 25^\circ\text{C}$  |      | 1.26 | V             |
|            |  | $I_F = 30\text{ A}$  |           |                              |      | 1.51 | V             |
|            |  | $I_F = 15\text{ A}$  |           | $T_{VJ} = 150^\circ\text{C}$ |      | 1.01 | V             |
|            |  | $I_F = 30\text{ A}$  |           |                              |      | 1.29 | V             |
| $I_{FAV}$  | average forward current                      | $T_C = 145^\circ\text{C}$<br>rectangular                           | $d = 0.5$ | $T_{VJ} = 175^\circ\text{C}$ |      | 15   | A             |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                                  |           |                              |      | 0.69 | V             |
| $r_F$      | slope resistance                             |  |           |                              |      | 18   | m $\Omega$    |
| $R_{thJC}$ | thermal resistance junction to case          |  |           |                              |      | 1.7  | K/W           |
| $R_{thCH}$ | thermal resistance case to heatsink          |  |           |                              |      | 0.5  | K/W           |
| $P_{tot}$  | total power dissipation                      |  |           | $T_C = 25^\circ\text{C}$     |      | 90   | W             |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$ |           | $T_{VJ} = 45^\circ\text{C}$  |      | 240  | A             |
| $C_J$      | junction capacitance                         | $V_R = 150\text{ V}$ $f = 1\text{ MHz}$                            |           | $T_{VJ} = 25^\circ\text{C}$  |      | 20   | pF            |
| $I_{RM}$   | max. reverse recovery current                | } $I_F = 15\text{ A}; V_R = 130\text{ V}$                          |           | $T_{VJ} = 25^\circ\text{C}$  |      | 3    | A             |
|            |  |  |           | $T_{VJ} = 125^\circ\text{C}$ |      | 6.5  | A             |
| $t_{rr}$   | reverse recovery time                        | } $-di_F/dt = 200\text{ A}/\mu\text{s}$                            |           | $T_{VJ} = 25^\circ\text{C}$  |      | 35   | ns            |
|            |  |  |           | $T_{VJ} = 125^\circ\text{C}$ |      | 55   | ns            |



| Package TO-220 |                              |                            | Ratings |      |      |      |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol         | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$      | RMS current                  | per terminal <sup>1)</sup> |         |      | 35   | A    |
| $T_{VJ}$       | virtual junction temperature |                            | -55     |      | 175  | °C   |
| $T_{op}$       | operation temperature        |                            | -55     |      | 150  | °C   |
| $T_{stg}$      | storage temperature          |                            | -55     |      | 150  | °C   |
| <b>Weight</b>  |                              |                            |         | 2    |      | g    |
| $M_D$          | mounting torque              |                            | 0.4     |      | 0.6  | Nm   |
| $F_C$          | mounting force with clip     |                            | 20      |      | 60   | N    |

**Product Marking**



**Part description**

- D = Diode
- P = HiPerFRED
- G = extreme fast
- 30 = Current Rating [A]
- C = Common Cathode
- 200 = Reverse Voltage [V]
- PB = TO-220AB (3)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DPG30C200PB     | DPG30C200PB        | Tube          | 50       | 505804   |

| Similar Part | Package              | Voltage class |
|--------------|----------------------|---------------|
| DPG30C200PC  | TO-263AB (D2Pak) (2) | 200           |
| DPG30C200HB  | TO-247AD (3)         | 200           |

**Equivalent Circuits for Simulation**

*\* on die level*

$T_{VJ} = 175^{\circ}C$

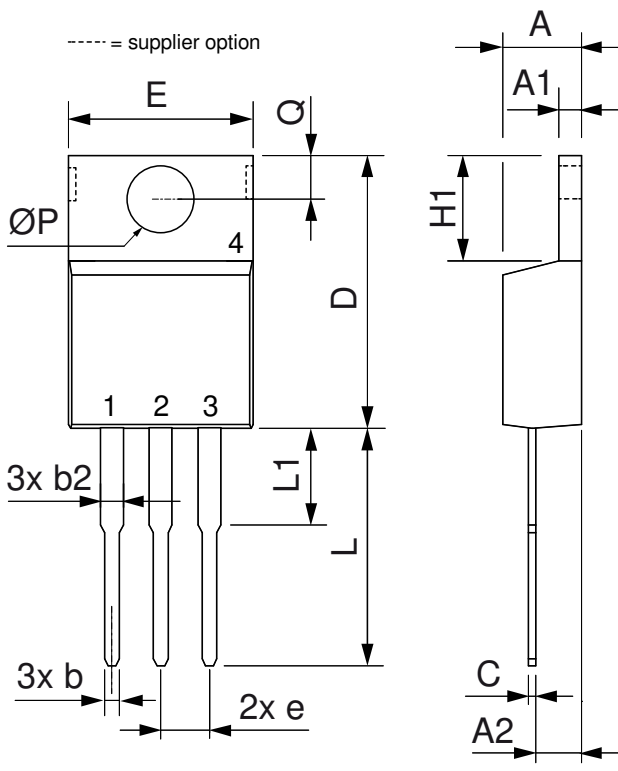


**Fast Diode**

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.69 | V  |
| $R_{0\ max}$ | slope resistance * | 14.7 | mΩ |



**Outlines TO-220**



| Dim. | Millimeter |       | Inches |       |
|------|------------|-------|--------|-------|
|      | Min.       | Max.  | Min.   | Max.  |
| A    | 4.32       | 4.82  | 0.170  | 0.190 |
| A1   | 1.14       | 1.39  | 0.045  | 0.055 |
| A2   | 2.29       | 2.79  | 0.090  | 0.110 |
| b    | 0.64       | 1.01  | 0.025  | 0.040 |
| b2   | 1.15       | 1.65  | 0.045  | 0.065 |
| C    | 0.35       | 0.56  | 0.014  | 0.022 |
| D    | 14.73      | 16.00 | 0.580  | 0.630 |
| E    | 9.91       | 10.66 | 0.390  | 0.420 |
| e    | 2.54       | BSC   | 0.100  | BSC   |
| H1   | 5.85       | 6.85  | 0.230  | 0.270 |
| L    | 12.70      | 13.97 | 0.500  | 0.550 |
| L1   | 2.79       | 5.84  | 0.110  | 0.230 |
| ØP   | 3.54       | 4.08  | 0.139  | 0.161 |
| Q    | 2.54       | 3.18  | 0.100  | 0.125 |



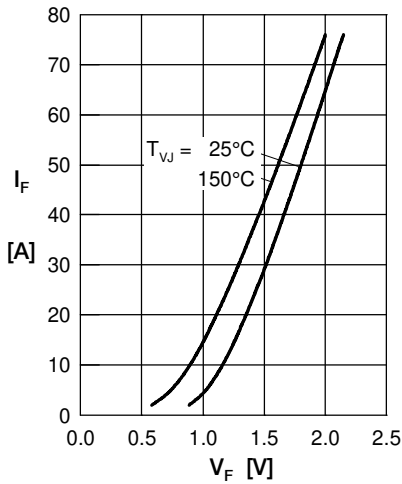
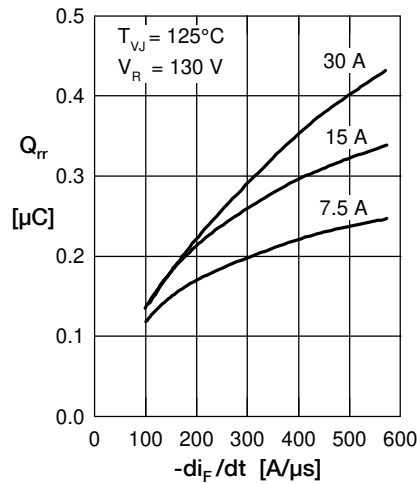
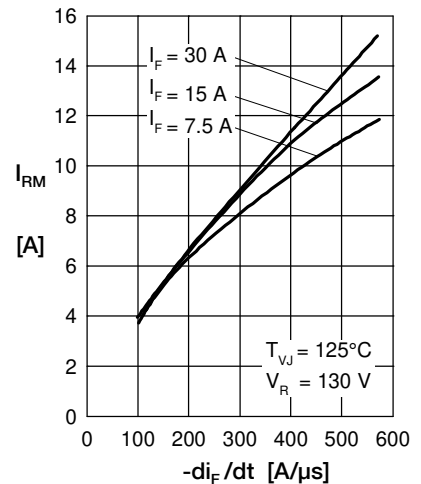
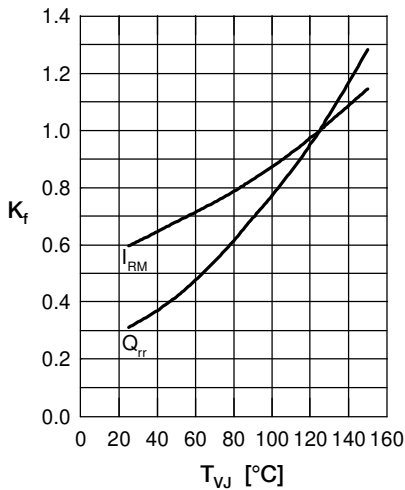
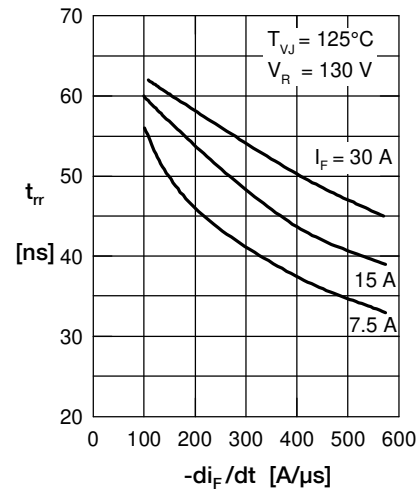
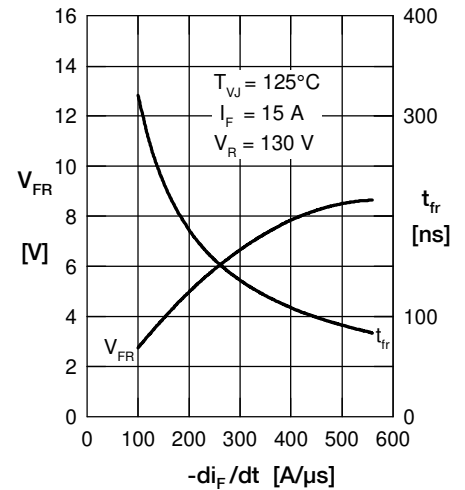
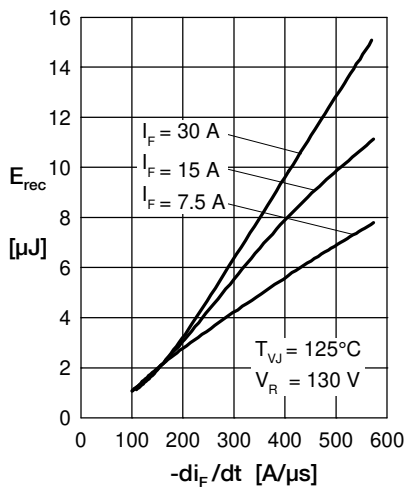
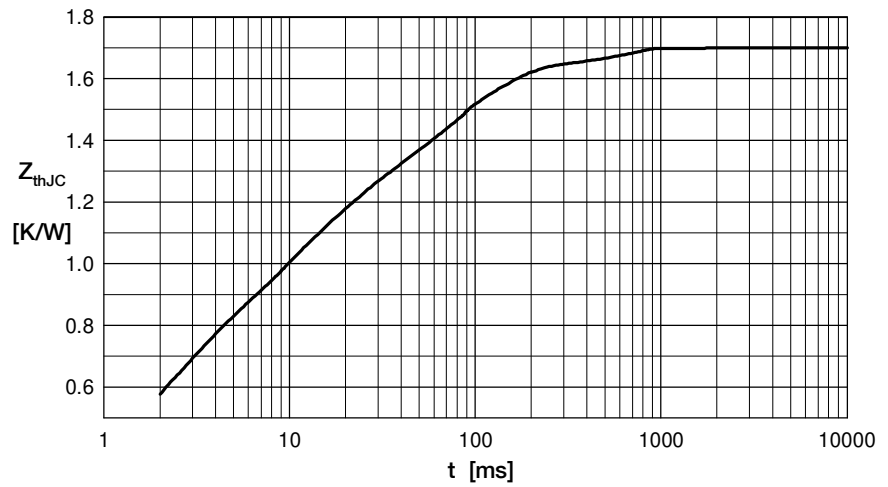
**Fast Diode**

 Fig. 1 Forward current  $I_F$  versus  $V_F$ 

 Fig. 2 Typ. reverse recov. charge  $Q_{rr}$  versus  $-di_F/dt$ 

 Fig. 3 Typ. peak reverse current  $I_{RM}$  versus  $-di_F/dt$ 

 Fig. 4 Typ. dynamic parameters  $Q_{rr}$ ,  $I_{RM}$  versus  $T_{VJ}$ 

 Fig. 5 Typ. recovery time  $t_{tr}$  versus  $-di_F/dt$ 

 Fig. 6 Typ. peak forward voltage  $V_{FR}$  and  $t_{tr}$  versus  $di_F/dt$ 

 Fig. 7 Typ. recovery energy  $E_{rec}$  versus  $-di_F/dt$ 


Fig. 8 Transient thermal resistance junction to case